# 74HC1GU04

#### Inverter

Rev. 05 — 10 July 2007

**Product data sheet** 

## 1. General description

The 74HC1GU04 is a high-speed Si-gate CMOS device. It provides an inverting single stage function. The standard output currents are half those of the 74HCU04.

#### 2. Features

- Symmetrical output impedance
- Wide operating voltage range from 2.0 V to 6.0 V
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options

## 3. Ordering information

Table 1. Ordering information

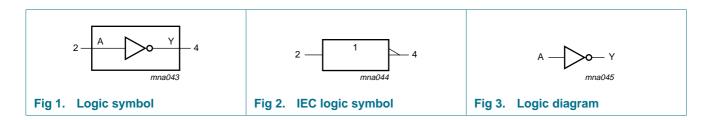
| Type number | Package           |        |   |          |  |  |  |  |
|-------------|-------------------|--------|---|----------|--|--|--|--|
|             | Temperature range | Name   | Description   | Version  |  |  |  |  |
| 74HC1GU04GW | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package;<br>5 leads; body width 1.25 mm | SOT353-1 |  |  |  |  |
| 74HC1GU04GV | –40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads                                  | SOT753   |  |  |  |  |

## 4. Marking

Table 2. Marking codes

| Type number | Marking |
|-------------|---------|
| 74HC1GU04GW | HD      |
| 74HC1GU04GV | HU4     |

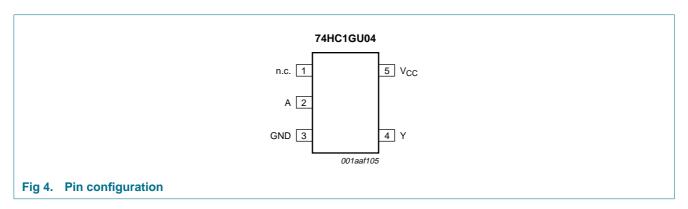
## 5. Functional diagram





# 6. Pinning information

## 6.1 Pinning



#### 6.2 Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| n.c.            | 1   | not connected  |
| A               | 2   | data input     |
| GND             | 3   | ground (0 V)   |
| Υ               | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |

# 7. Functional description

#### Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level$ 

| Input | Output |
|-------|--------|
| A     | Υ      |
| L     | Н      |
| Н     | L      |

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions  | Min          | Max   | Unit |
|------------------|-------------------------|---|--------------|-------|------|
| $V_{CC}$         | supply voltage          |   | -0.5         | +7.0  | V    |
| I <sub>IK</sub>  | input clamping current  | $V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$                       | <u>[1]</u> _ | ±20   | mA   |
| I <sub>OK</sub>  | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$                       | <u>[1]</u> _ | ±20   | mA   |
| Io               | output current          | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ | <u>[1]</u> _ | ±12.5 | mA   |
| I <sub>CC</sub>  | supply current          |   | -            | 25    | mA   |
| $I_{GND}$        | ground current          |   | -25          | -     | mA   |
| T <sub>stg</sub> | storage temperature     |   | -65          | +150  | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$                   | [2] _        | 200   | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol              | Parameter                           | Conditions  | Min | Тур | Max        | Unit         |
|---------------------|-------------------------------------|---|-----|-----|------------|--------------|
| $V_{CC}$            | supply voltage                      |   | 2.0 | 5.0 | 6.0        | V            |
| VI                  | input voltage                       |   | 0   | -   | $V_{CC}$   | V            |
| Vo                  | output voltage                      |   | 0   | -   | $V_{CC}$   | V            |
| T <sub>amb</sub>    | ambient temperature                 |   | -40 | +25 | +125       | °C           |
| $\Delta t/\Delta V$ |                                     |   |     |     |            |              |
| $\Delta t/\Delta V$ | input transition rise and fall      | V <sub>CC</sub> = 2.0 V                           | -   | -   | 625        | ns/V         |
| Δt/ΔV               | input transition rise and fall rate | $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ | -   | -   | 625<br>139 | ns/V<br>ns/V |

#### 10. Static characteristics

 Table 7.
 Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T<sub>amb</sub> = 25 °C.

| Symbol   | Parameter        | Conditions               | -40 °C to +85 °C |     |     | –40 °C t | Unit |   |
|----------|------------------|--------------------------|------------------|-----|-----|----------|------|---|
|          |                  |                          | Min              | Тур | Max | Min      | Max  |   |
| $V_{IH}$ | HIGH-level input | $V_{CC} = 2.0 \text{ V}$ | 1.7              | 1.4 | -   | 1.7      | -    | V |
| volta    | voltage          | V <sub>CC</sub> = 4.5 V  | 3.6              | 2.6 | -   | 3.6      | -    | V |
|          |                  | V <sub>CC</sub> = 6.0 V  | 4.8              | 3.4 | -   | 4.8      | -    | V |
| $V_{IL}$ | LOW-level input  | $V_{CC} = 2.0 \text{ V}$ | -                | 0.6 | 0.3 | -        | 0.3  | V |
|          | voltage          | $V_{CC} = 4.5 \text{ V}$ | -                | 1.9 | 0.9 | -        | 0.9  | V |
|          |                  | V <sub>CC</sub> = 6.0 V  | -                | 2.6 | 1.2 | -        | 1.2  | V |

<sup>[2]</sup> Above 55  $^{\circ}$ C the value of P<sub>tot</sub> derates linearity with 2.5 mW/K.

 Table 7.
 Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{amb}$  = 25 °C.

| Symbol          | Parameter                | Conditions   | -40  | –40 °C to +85 °C |      |     | –40 °C to +125 °C |    |  |
|-----------------|--------------------------|--|------|------------------|------|-----|-------------------|----|--|
|                 |                          |  | Min  | Тур              | Max  | Min | Max               |    |  |
| $V_{OH}$        | HIGH-level output        | $V_I = V_{IH}$ or $V_{IL}$                                   |      |                  |      |     |                   |    |  |
|                 | voltage                  | $I_{O} = -20 \mu A; V_{CC} = 2.0 V$                          | 1.8  | 2.0              | -    | 1.8 | -                 | V  |  |
|                 |                          | $I_O = -20 \mu A; V_{CC} = 4.5 V$                            | 4.0  | 4.5              | -    | 4.0 | -                 | V  |  |
|                 |                          | $I_{O} = -20 \mu A; V_{CC} = 6.0 V$                          | 5.5  | 6.0              | -    | 5.5 | -                 | V  |  |
|                 |                          | $I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$            | 4.13 | 4.32             | -    | 3.7 | -                 | V  |  |
|                 |                          | $I_{O} = -2.6 \text{ mA}; V_{CC} = 6.0 \text{ V}$            | 5.63 | 5.81             | -    | 5.2 | -                 | V  |  |
| V <sub>OL</sub> | LOW-level output voltage | $V_I = V_{IH}$ or $V_{IL}$                                   |      |                  |      |     |                   |    |  |
|                 |                          | $I_O = 20 \mu A; V_{CC} = 2.0 V$                             | -    | 0                | 0.2  | -   | 0.2               | V  |  |
|                 |                          | $I_O = 20 \mu A; V_{CC} = 4.5 V$                             | -    | 0                | 0.5  | -   | 0.5               | V  |  |
|                 |                          | $I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$                     | -    | 0                | 0.5  | -   | 0.5               | V  |  |
|                 |                          | $I_{O} = 2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$             | -    | 0.15             | 0.33 | -   | 0.4               | V  |  |
|                 |                          | $I_{O} = 2.6 \text{ mA}; V_{CC} = 6.0 \text{ V}$             | -    | 0.16             | 0.33 | -   | 0.4               | V  |  |
| I <sub>I</sub>  | input leakage current    | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$              | -    | -                | 1.0  | -   | 1.0               | μΑ |  |
| I <sub>CC</sub> | supply current           | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$ | -    | -                | 10   | -   | 20                | μΑ |  |
| C <sub>I</sub>  | input capacitance        |  | -    | 5                | -    | -   | -                 | pF |  |

# 11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V;  $t_r = t_f = 6.0$  ns; For test circuit see Figure 6. All typical values are measured at  $T_{amb} = 25$  °C.

| Parameter                         | Conditions                                    |   | –40 °C to +85 °C   |   |     | -40 °C to +125 °C  |  | Unit  |
|-----------------------------------|---|---|--|---|-----|--|--|---|
|                                   |   |   | Min  | Тур   | Max | Min  | Max  |   |
| t <sub>pd</sub> propagation delay | A to Y; see Figure 5                          | [1]   |  |   |     |  |  |   |
|                                   | $V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$ |   | -  | 10  | 90  | -  | 105  | ns  |
|                                   | $V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$ |   | -  | 7   | 18  | -  | 21   | ns  |
|                                   | $V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$ |   | -  | 6   | 15  | -  | 18   | ns  |
|                                   | $V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$ |   | -  | 5   | -   | -  | -  | ns  |
| power dissipation capacitance     | $V_I = GND$ to $V_{CC}$                       | [2]   | -  | 14  | -   | -  | -  | pF  |
|                                   | propagation delay                             | propagation delay A to Y; see Figure 5 $V_{CC} = 2.0 \text{ V; } C_L = 50 \text{ pF}$ $V_{CC} = 4.5 \text{ V; } C_L = 50 \text{ pF}$ $V_{CC} = 6.0 \text{ V; } C_L = 50 \text{ pF}$ $V_{CC} = 6.0 \text{ V; } C_L = 50 \text{ pF}$ $V_{CC} = 5.0 \text{ V; } C_L = 15 \text{ pF}$ power dissipation $V_I = \text{GND to } V_{CC}$ | propagation delay A to Y; see Figure 5 [1] $V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$ $V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$ $V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$ $V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$ power dissipation $V_I = \text{GND to } V_{CC}$ [2] | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ |     | $\begin{array}{ c c c c c c }\hline & & & & & & & & & & & & & & & & & & &$ | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $ \begin{array}{ c c c c c c c c c c c c c c c c c c c$ |

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

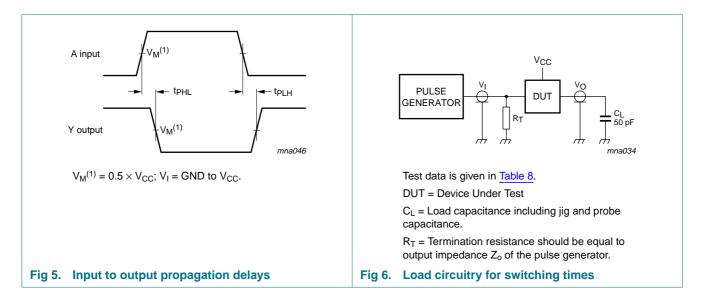
fo = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

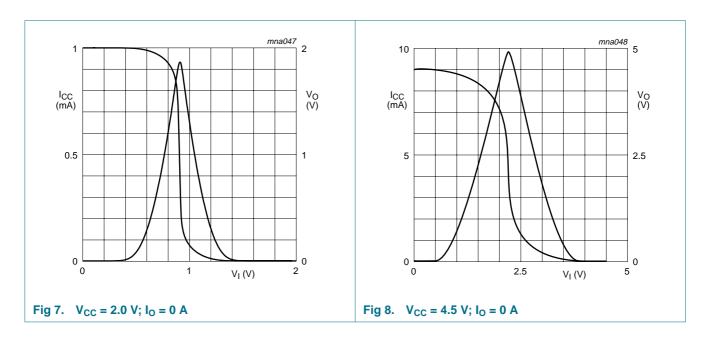
V<sub>CC</sub> = supply voltage in Volts.

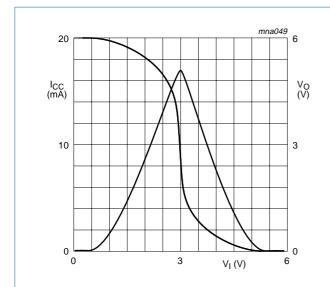
<sup>[2]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu W$ ).

## 12. Waveforms



# 13. Typical transfer characteristics





Rbias =  $560 \text{ k}\Omega$   $\begin{array}{c} \text{VCC} \\ \text{VCC} \\ \text{(f = 1 kHz)} \\ \text{O} \end{array}$ 

Fig 9.  $V_{CC} = 6.0 \text{ V}$ ;  $I_{O} = 0 \text{ A}$ 

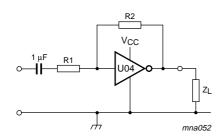
Fig 10. Test set-up for measuring forward transfer conductance  $g_{fs} = \Delta I_O/\Delta V_I$  at  $V_O$  is constant

# 14. Application information

Some applications are:

- Linear amplifier (see Figure 11)
- In crystal oscillator design (see Figure 12)

Remark: All values given are typical unless otherwise specified



Maximum  $V_{o(p-p)} = V_{CC} - 1.5 \text{ V}$  centered at  $0.5 \times V_{CC}.$ 

$$G_v = -\frac{G_{ol}}{1 + \frac{Rl}{R2}(1 + G_{ol})}$$

Gol = open loop gain

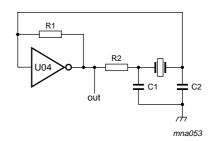
G<sub>v</sub> = voltage gain

 $R1 \ge 3 \text{ k}\Omega$ ,  $R2 \le 1 \text{ M}\Omega$ 

 $Z_L > 10 \text{ k}Ω$ ;  $G_{ol} = 20 \text{ (typ.)}$ 

Typical unity gain bandwidth product is 5 MHz.

Fig 11. Used as a linear amplifier



C1 = 47 pF (typ.)

C2 = 22 pF (typ.)

R1 = 1 M $\Omega$  to 10 M $\Omega$  (typ.)

R2 optimum value depends on the frequency and required stability against changes in  $V_{CC}$  or average minimum  $I_{CC}$  ( $I_{CC}$  is typically 2 mA at  $V_{CC}$  = 3 V and f = 1 MHz).

Fig 12. Crystal oscillator configuration

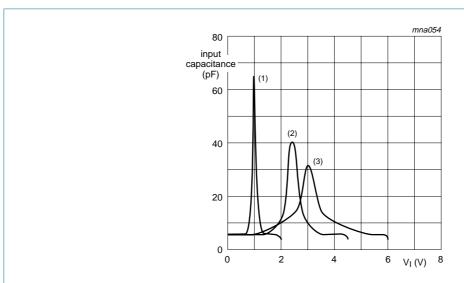
Table 9. External components for resonator (f < 1 MHz)

All values given are typical and must be used as an initial set-up

| Frequency            | R1                   | R2             | C1    | C2    |
|----------------------|----------------------|----------------|-------|-------|
| 10 kHz to 15.9 kHz   | $2.2~\text{M}\Omega$ | 220 k $\Omega$ | 56 pF | 20 pF |
| 16 kHz to 24.9 kHz   | $2.2~\text{M}\Omega$ | 220 k $\Omega$ | 56 pF | 10 pF |
| 25 kHz to 54.9 kHz   | $2.2~\text{M}\Omega$ | 100 kΩ         | 56 pF | 10 pF |
| 55 kHz to 129.9 kHz  | $2.2~\text{M}\Omega$ | 100 kΩ         | 47 pF | 5 pF  |
| 130 kHz to 199.9 kHz | $2.2~\text{M}\Omega$ | 47 kΩ          | 47 pF | 5 pF  |
| 200 kHz to 349.9 kHz | $2.2~\text{M}\Omega$ | 47 kΩ          | 47 pF | 5 pF  |
| 350 kHz to 600 kHz   | $2.2~\text{M}\Omega$ | 47 kΩ          | 47 pF | 5 pF  |

Table 10. Optimum value for R2

| Frequency | R2                     | Optimum for  |
|-----------|------------------------|--|
| 3 kHz     | $2.0~\text{k}\Omega$   | minimum required I <sub>CC</sub>                   |
|           | $8.0~\text{k}\Omega$   | minimum influence due to change in V <sub>CC</sub> |
| 6 kHz     | 1.0 k $\Omega$         | minimum required I <sub>CC</sub>                   |
|           | $4.7~\mathrm{k}\Omega$ | minimum influence by V <sub>CC</sub>               |
| 10 kHz    | $0.5~\mathrm{k}\Omega$ | minimum required I <sub>CC</sub>                   |
|           | $2.0~\text{k}\Omega$   | minimum influence by V <sub>CC</sub>               |
| 14 kHz    | $0.5~\mathrm{k}\Omega$ | minimum required I <sub>CC</sub>                   |
|           | 1.0 kΩ                 | minimum influence by V <sub>CC</sub>               |
| >14 kHz   | -                      | replace R2 by C3 with a typical value of 35 pF     |



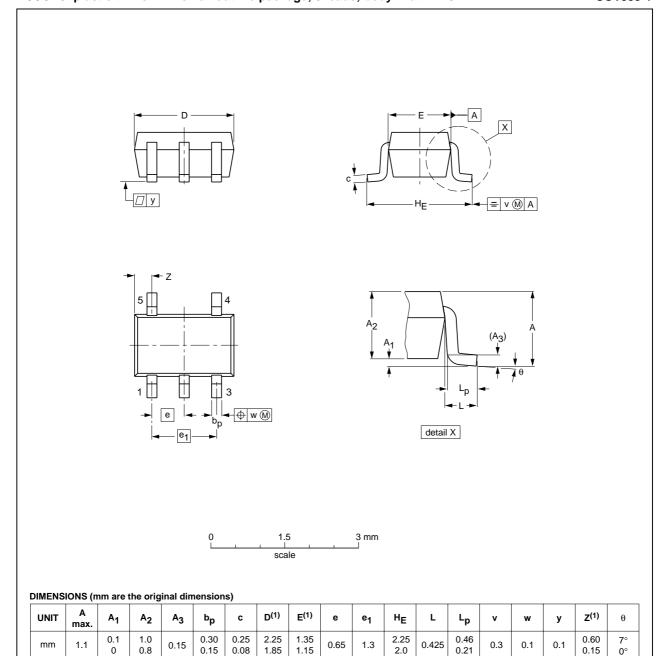
- (1)  $V_{CC} = 2.0 \text{ V}.$
- (2)  $V_{CC} = 4.5 \text{ V}.$
- (3)  $V_{CC} = 6.0 \text{ V}.$

Fig 13. Typical input capacitance as a function of the input voltage

# 15. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE  | REFER |        | REFERENCES |  | EUROPEAN   | ISSUE DATE                      |
|----------|-------|--------|------------|--|------------|---------------------------------|
| VERSION  | IEC   | JEDEC  | JEITA      |  | PROJECTION | ISSUE DATE                      |
| SOT353-1 |       | MO-203 | SC-88A     |  |            | <del>00-09-01</del><br>03-02-19 |

Fig 14. Package outline SOT353-1 (TSSOP5)

#### Plastic surface-mounted package; 5 leads

SOT753

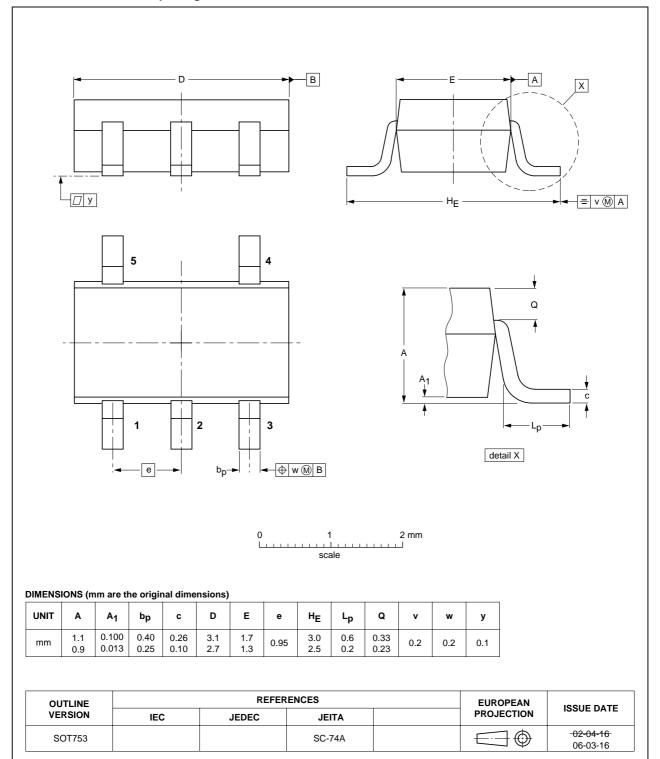


Fig 15. Package outline SOT753 (SC-74A)

# 16. Revision history

Table 11. Revision history

|                | •   |                       |               |             |  |  |
|----------------|---|-----------------------|---------------|-------------|--|--|
| Document ID    | Release date  | Data sheet status     | Change notice | Supersedes  |  |  |
| 74HC1GU04_5    | 20070710  | Product data sheet    | -             | 74HC1GU04_4 |  |  |
| Modifications: | <ul> <li>The format of this data sheet has been redesigned to comply with the new identity<br/>guidelines of NXP Semiconductors.</li> </ul> |                       |               |             |  |  |
|                | <ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>  |                       |               |             |  |  |
|                | <ul> <li>Package SOT353 changed to SOT353-1 in <u>Table 1</u> and <u>Figure 14</u>.</li> </ul>  |                       |               |             |  |  |
|                | <ul> <li>Quick Reference Data and Soldering sections removed.</li> </ul>  |                       |               |             |  |  |
|                | <ul> <li>Section 2 "Features" updated.</li> </ul>   |                       |               |             |  |  |
| 74HC1GU04_4    | 20020527  | Product specification | -             | 74HC1GU04_3 |  |  |
| 74HC1GU04_3    | 20020513  | Product specification | -             | 74HC1GU04_2 |  |  |
| 74HC1GU04_2    | 20010427  | Product specification | -             | 74HC1GU04_1 |  |  |
| 74HC1GU04_1    | 19981118  | Product specification | -             | -           |  |  |
|                |   |                       |               |             |  |  |

## 17. Legal information

#### 17.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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